

**Micro Commercial Components** 

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SI2304

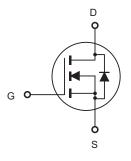
## Features

- Lead Free Finish/RoHS Compliant ("P" Suffix designates RoHS Compliant. See ordering information)
- Case Material:Molded Plastic. UL Flammability Classification Rating 94V-0 and MSL Rating 1
- 30V,2.5A,  $R_{DS(ON)}$ =65m  $\Omega @V_{GS}$ =10V 30V,2.0A,  $R_{DS(ON)}$ =90m  $\Omega @V_{GS}$ =4.5V
- High dense cell design for extremely low R<sub>DS(ON)</sub>
- Rugged and reliable
- Lead free product is acquired
- SOT-23 Package
- Marking Code: S4

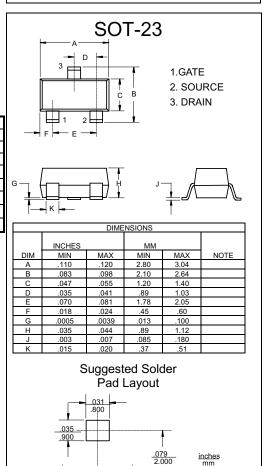
#### Maximum Ratings @ 25°C Unless Otherwise Specified

Symbol	Parameter	Rating	Unit
V <sub>DS</sub>	Drain-source Voltage	30	V
ID	Drain Current-Continuous	2.5	A
I <sub>DM</sub>	Drain Current-Pulsed	10	A
V <sub>GS</sub>	Gate-source Voltage	$\pm 20$	V
PD	Total Power Dissipation	0.25	W
R∘ <sub>JA</sub>	Thermal Resistance Junction to Ambient	500	°C/W
TJ	Operating Junction Temperature	-55 to +150	°C
T <sub>STG</sub>	Storage Temperature	-55 to +150	°C

### **Internal Block Diagram**



# N-Channel Enhancement Mode Field Effect Transistor



.037 .950



### **Revision: 1**



# SI2304

### **Electrical Characteristics** $T_A = 25^{\circ}C$ unless otherwise noted

Parameter	Symbol	Test Condition	Min	Тур	Мах	Units		
Off Characteristics								
Drain-Source Breakdown Voltage	BVDSS	Vgs = 0V, Id =250µA	30			V		
Zero Gate Voltage Drain Current	IDSS	VDS =30V, VGS =1V			1	μA		
Gate Body Leakage Current, Forward	IGSSF	Vgs = 20V, Vds = 0V			100	nA		
Gate Body Leakage Current, Reverse	Igssr	Vgs = -20V, Vds = 0V			-100	nA		
On Characteristics								
Gate Threshold Voltage	VGS(th)	Vgs = Vds, Id =250µA	1		3	V		
Static Drain-Source On-Resistance	RDS(on)	Vgs =10V, Id =2.5A			65	mΩ		
		Vgs =4.5V, ID =2A			90	mΩ		
Forward Transconductance	gfs	VDS =4.5V, ID =2.5A		4.6		S		
Dynamic Characteristics								
Input Capacitance	Ciss	- V <sub>DS</sub> =15V, V <sub>GS</sub> = 0V,		240		pF		
Output Capacitance	Coss			110		pF		
Reverse Transfer Capacitance	Crss	1 - 1.0 10112		17		pF		
Switching Characteristics								
Turn-On Delay Time	td(on)			8	20	ns		
Turn-On Rise Time	tr	VDD = 15V, ID =1A, VGEN =10V, RG=6Ω,		12	30	ns		
Turn-Off Delay Time	td(off)	$R_{L}=15\Omega$		17	35	ns		
Turn-Off Fall Time	tr	TKL=1322		8	20	ns		
Total Gate Charge	Qg			4.5	10	nC		
Gate-Source Charge	Qgs	VDS =15V, ID =2.5A, VGS =10V		0.8		nC		
Gate-Drain Charge	Qgd	VGS - IUV		1.0		nC		
Drain-Source Diode Characteristics and Maximun Ratings								
Drain-Source Diode Forward Voltage	Vsd	Vgs = 0V, Is =1.25A			1.2	V		

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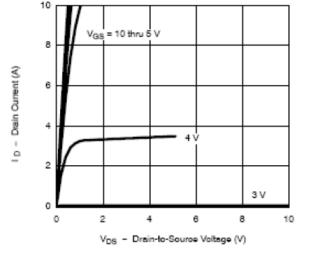
Downloaded from Elcodis.com electronic components distributor



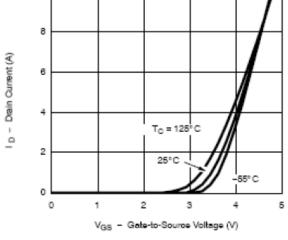
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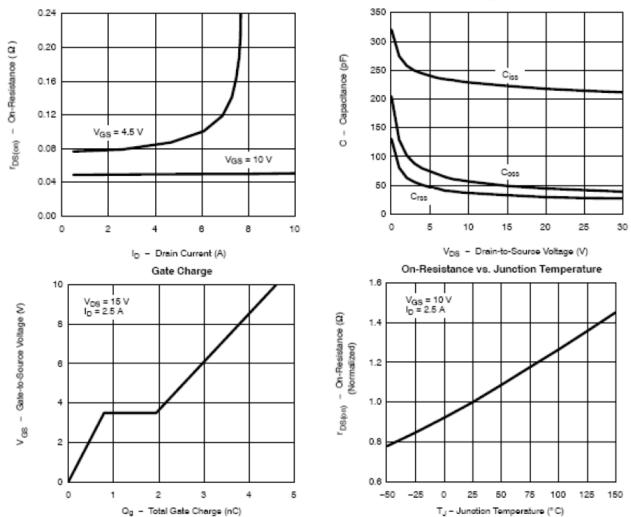


Output Characteristics



Capacitance



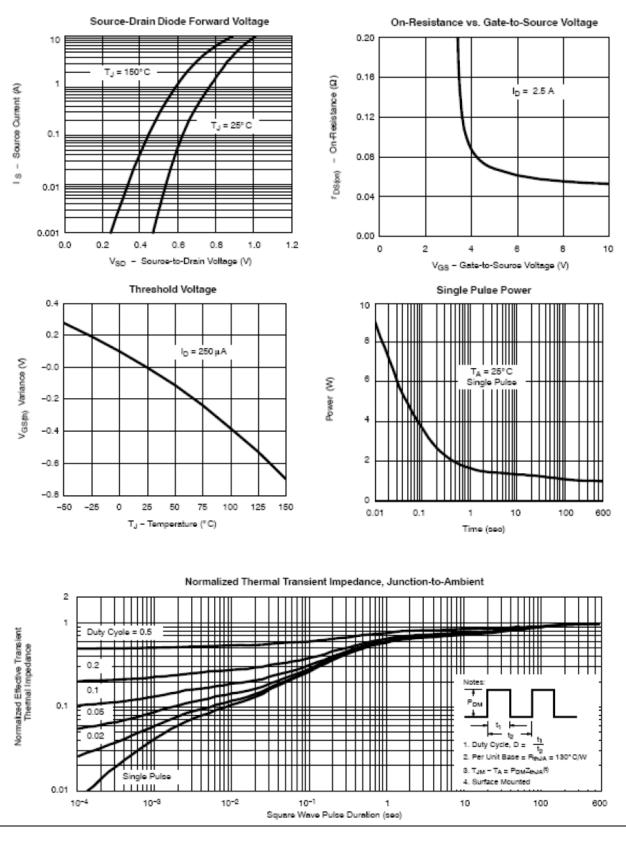


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#### **Revision: 1**



### **Ordering Information**

Device	Packing		
(Part Number)-TP	Tape&Reel3Kpcs/Reel		

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